

300V 70A N-Channel Enhancement Mode Power MOSFET

Description

The AKT70N30H is an N-Channel enhancement mode power MOSFET which using proprietary planar stripe and DMOS technology.

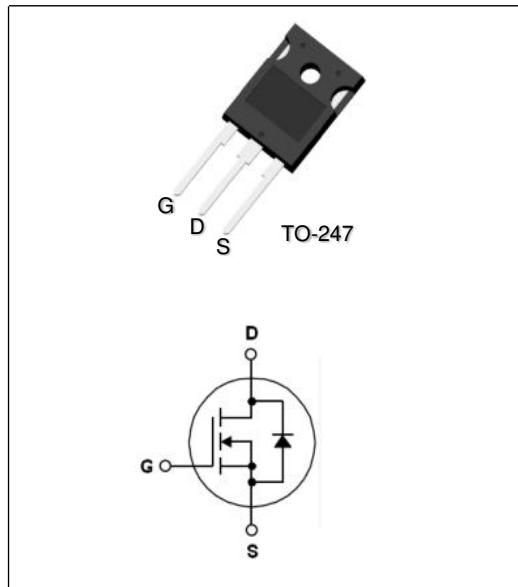
This MOSFET has low static on-resistance and high avalanche energy strength. This device provide excellent switching performance for UPS,DC-DC converters and AC-DC power supply.

Features

- Low on-Resistance: $R_{DS(on)}=36.8\text{m}\Omega(\text{typ.})$
- Special Process Technology for high ESD Capability
- 100% Avalanche Test
- Good Stability and Uniformity with High E_{AS}

Applications

- UPS Applications
- DC-DC Converters and AC-DC Power Supply



Absolute Maximum Ratings @ $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter		Ratings	Unit
V_{DSS}	Drain to Source Voltage		300	V
V_{GSS}	Gate to Source Voltage		± 30	V
I_D	Drain Current	$T_C=25^\circ\text{C}$	70	A
		$T_C=100^\circ\text{C}$	49	A
I_{DM}	Pulsed Drain Current	(Note1)	280	A
P_D	Maximum Power Dissipation	$T_C=25^\circ\text{C}$	295	W
	Derate above 25°C		2.1	W/ $^\circ\text{C}$
E_{AS}	Single Pulsed Avalanche Energy	(Note 2)	2000	mJ
T_J	Operating Junction Temperature Range		-55~+150	$^\circ\text{C}$
T_{STG}	Storage Temperature Range		-55~+150	$^\circ\text{C}$

Thermal Characteristics

Symbol	Parameter	Ratings	Unit
$R_{th(J-C)}$	Thermal Resistance, Junction to case	0.42	$^\circ\text{C}/\text{W}$
$R_{th(J-A)}$	Thermal Resistance, Junction to Ambient	40	$^\circ\text{C}/\text{W}$

Electrical Characteristics @ $T_C=25\text{ }^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
BV_{DSS}	Drain to Source Breakdown Voltage	$V_{GS}=0\text{V}, I_D=250\mu\text{A}$	300	-	-	V
$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{DS}=V_{GS}, I_D=250\mu\text{A}$	2.5	-	4	V
$R_{DS(on)}$	Static Drain-Source On-Resistance	$V_{GS}=10\text{V}, I_D=35\text{A}$	-	36.8	-	$\text{m}\Omega$
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=300\text{V}, V_{GS}=0\text{V}$	-	-	1	μA
I_{GSS}	Gate to Source Leakage Current	$V_{GS}=\pm 30\text{V}, V_{DS}=0\text{V}$	-	-	± 100	nA

D-S Diode Characteristics and Maximum Rating @ $T_C=25\text{ }^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
I_S	Maximum Drain to Source Diode Forward Current		-	-	70	A
V_{SD}	Drain-Source Diode Forward Voltage	$V_{GS}=0\text{V}, I_S=70\text{A}$	-	-	1.2	V
t_{rr}	Reverse Recovery Time		-	99	-	ns
Q_{rr}	Reverse Recovery Charge	$V_{GS}=0\text{V}, I_S=70\text{A}, \frac{dI}{dt}=-100\text{A}/\text{us}$	-	265	-	nC

Switching Characteristics @ $T_C=25\text{ }^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$	Turn-on Delay Time	$I_D=70\text{A}, V_{DD}=150\text{V}, R_G=25\Omega$ (Note 3)	-	42	-	ns
t_r	Rising Time		-	171	-	ns
$t_{d(off)}$	Turn-off Delay Time		-	101	-	ns
t_f	Falling Time		-	23	-	ns
C_{iss}	Input Capacitance	$V_{GS}=0\text{V}, V_{DS}=25\text{V}, f=1.0\text{MHz}$	-	4500	-	pF
C_{oss}	Output Capacitance		-	595	-	pF
C_{rss}	Reverse Transfer Capacitance		-	10	-	pF
Q_g	Total Gate Charge	$I_D=70\text{A}, V_{DS}=240\text{V}$ $V_{GS}=10\text{V}$ (Note 3)	-	63	-	nC
Q_{gs}	Gate to Source Charge		-	23	-	nC
Q_{gd}	Gate to Drain Charge		-	23	-	nC

Note:

1. Repetitive rating: pulse-width limited by maximum junction temperature
2. L=2mH, $V_{DD}=100\text{V}$, $V_G=10\text{V}$, @ $T_C=25\text{ }^\circ\text{C}$
3. Essentially independent of operating temperature typical characteristics

Typical Performance Characteristics

Fig. 1. Typical on-Resistance Characteristics

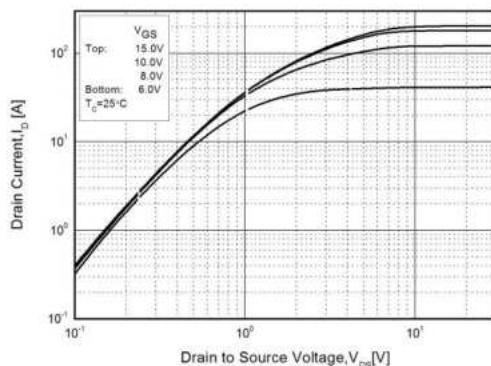


Fig. 3. Static on-Resistance vs. I_D

Fig. 2. Typical Transfer Characteristics

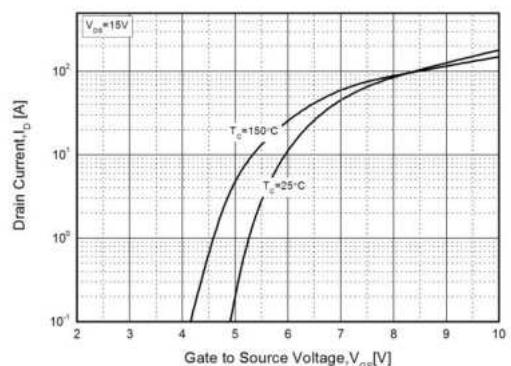


Fig. 4. Body Diode Forward Voltage vs. I_{DR}

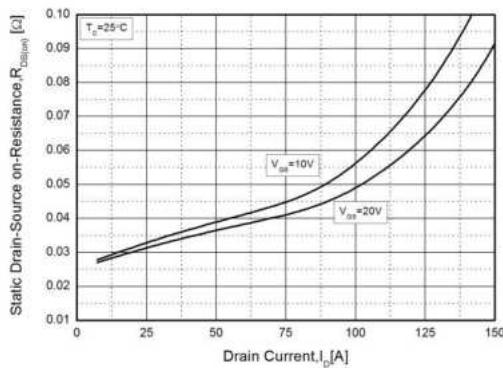


Fig. 5. Capacitance Characteristics

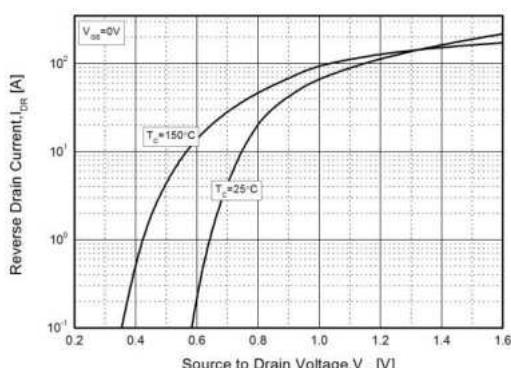
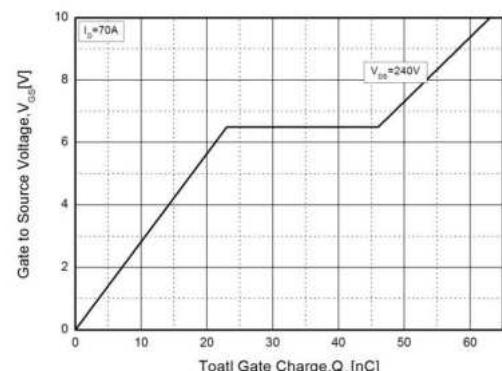
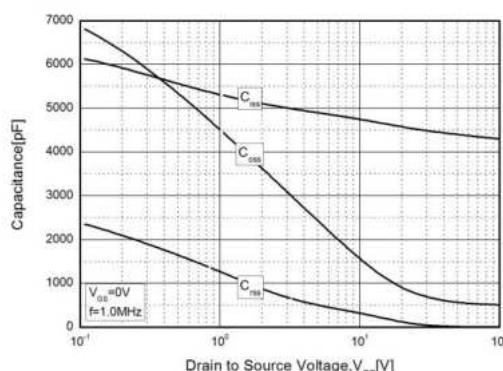


Fig. 6. Gate Charge Characteristics



Typical Performance Characteristics

Fig. 7. Breakdown Voltage vs. Temperature

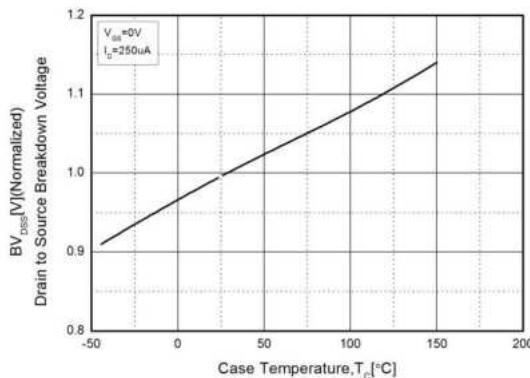


Fig. 8. Static on-Resistance vs. Temperature

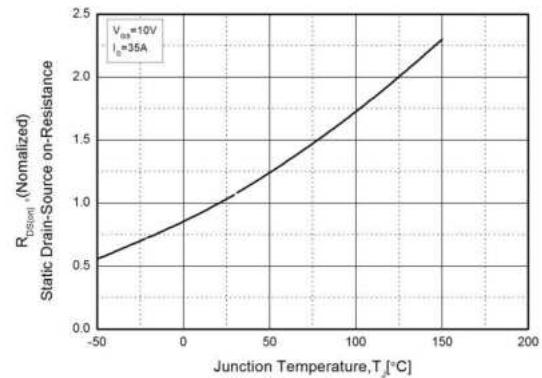


Fig. 9. Maximum Safe Operating Area

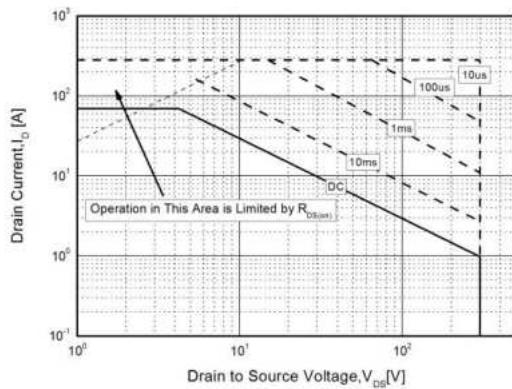


Fig. 10. Maximum Drain Current vs. Temperature

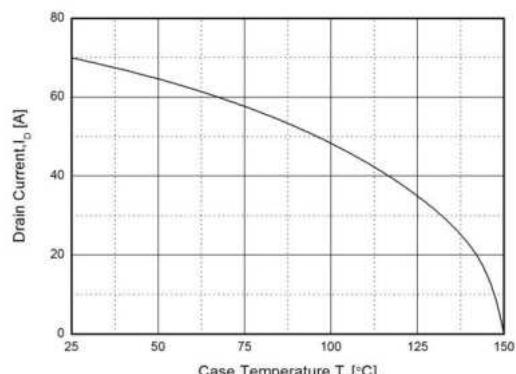
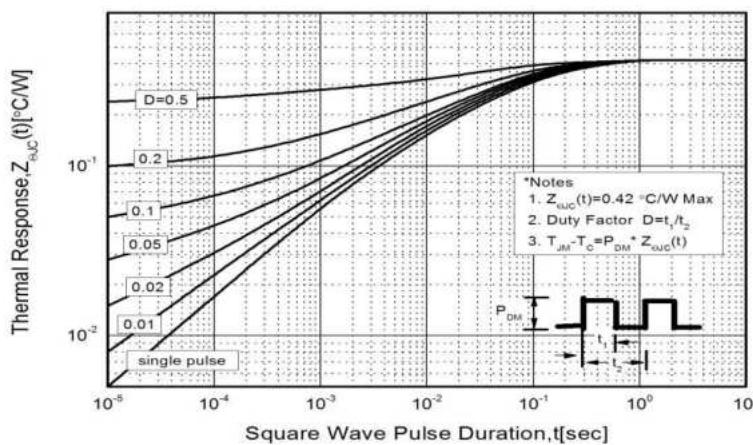


Fig. 11. Transient Thermal Response Curve



Package Dimensions**TO-247**

(Dimensions in Millimeters)

